

# **High Voltage Switching Diode**

## BAS19L, BAS20L, BAS21L, **BAS21DW5**

#### **Features**

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS
- S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Continuous Reverse Voltage  BAS19  BAS20  BAS21	V <sub>R</sub>	120 200 250	Vdc
Repetitive Peak Reverse Voltage BAS19 BAS20 BAS21	$V_{RRM}$	120 200 250	Vdc
Continuous Forward Current	I <sub>F</sub>	200	mAdc
Peak Forward Surge Current (1/2 Cycle, Sine Wave, 60 Hz)	I <sub>FSM</sub>	2	Α
Repetitive Peak Forward Current (Pulse Train: T <sub>ON</sub> = 1 s, T <sub>OFF</sub> = 0.5 s)	I <sub>FRM</sub>	0.6	Α
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
Power Dissipation (Note 1)	P <sub>D</sub>	385	mW
Electrostatic Discharge	ESD	HM < 500	V
		MM < 400	V

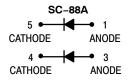
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

1. Mounted on FR-5 Board = 1.0 x 0.75 x 0.062 in.

## **HIGH VOLTAGE SWITCHING DIODE**





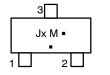




SOT-23 (TO-236) **CASE 318** STYLE 8

SC-88A (SOT-353) CASE 419A

#### **MARKING DIAGRAMS**





= P, R, or S = BAS19L = BAS20L R

S = BAS21L or BAS21DW5

= Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon the manufacturing location.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

## BAS19L, BAS20L, BAS21L, BAS21DW5

## THERMAL CHARACTERISTICS (SOT-23)

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board	$P_{D}$	225	mW
(Note 2) $T_A = 25^{\circ}C$ Derate above 25°C		1.8	mW/°C
Thermal Resistance Junction-to-Ambient (SOT-23)	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 3)	P <sub>D</sub>	300	mW
T <sub>A</sub> = 25°C Derate above 25°C		2.4	mW/°C
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

## THERMAL CHARACTERISTICS (SC-88A)

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 4)	$P_{D}$	385	mW
Thermal Resistance – Junction-to-Ambient Derate Above 25°C	$R_{ heta JA}$	328 3.0	°C/W mW/°C
Maximum Junction Temperature	T <sub>Jmax</sub>	150	°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

<sup>2.</sup> FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

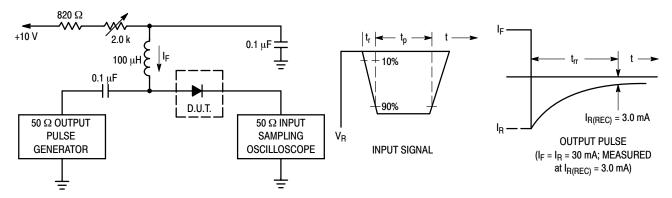
Characteristic	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current	I <sub>R</sub>			μAdc
(V <sub>R</sub> = 100 Vdc) BAS19		_	0.1	
(V <sub>R</sub> = 150 Vdc) BAS20		_	0.1	
(V <sub>R</sub> = 200 Vdc) BAS21		_	0.1	
$(V_R = 100 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BAS19		_	100	
$(V_R = 150 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BAS20		_	100	
$(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BAS21		_	100	
Reverse Breakdown Voltage	V <sub>(BR)</sub>			Vdc
(I <sub>BR</sub> = 100 μAdc) BAS19		120	_	
(I <sub>BR</sub> = 100 μAdc) BAS20		200	_	
(I <sub>BR</sub> = 100 μAdc) BAS21		250	-	
Forward Voltage	V <sub>F</sub>			Vdc
(I <sub>F</sub> = 100 mAdc)		_	1.0	
(I <sub>F</sub> = 200 mAdc)		-	1.25	
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)	C <sub>D</sub>	-	5.0	pF
Reverse Recovery Time ( $I_F = I_R = 30 \text{ mAdc}$ , $I_{R(REC)} = 3.0 \text{ mAdc}$ , $R_L = 100$ )	t <sub>rr</sub>	-	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

<sup>3.</sup> Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

<sup>4.</sup> Mounted on FR-5 Board =  $1.0 \times 0.75 \times 0.062$  in.

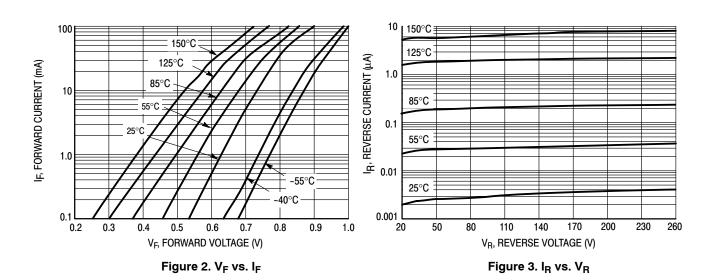
## BAS19L, BAS20L, BAS21L, BAS21DW5



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 30 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.
- 3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit



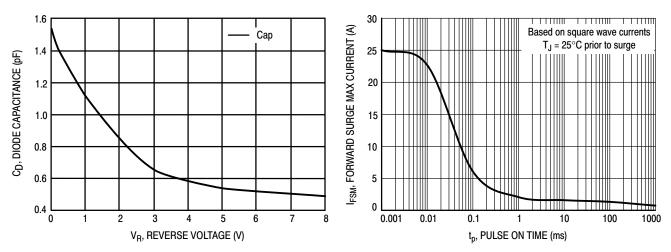


Figure 4. Capacitance

Figure 5. Forward Surge Current

## BAS19L, BAS20L, BAS21L, BAS21DW5

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BAS19LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS19LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
NSVBAS19LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS20LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS20LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
NSVBAS20LT3G*	SOT-23 (Pb-Free)	10000 / Tape & Reel
SBAS20LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS21LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SBAS21LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel
BAS21LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
SBAS21LT3G*	SOT-23 (Pb-Free)	10000 / Tape & Reel
BAS21DW5T1G	SC-88A (Pb-Free)	3000 / Tape & Reel
SBAS21DW5T1G*	SC-88A (Pb-Free)	3000 / Tape & Reel
SBAS21DW5T3G*	SC-88A (Pb-Free)	10000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified

and PPAP Capable.

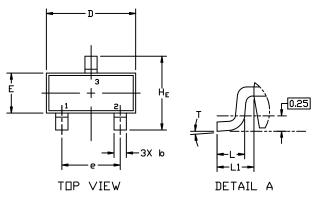




**SOT-23 (TO-236)** CASE 318 ISSUE AT

**DATE 01 MAR 2023** 









#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIM	IETERS		INCHES		
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Ε	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10°	0*		10°

## GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

#### **STYLES ON PAGE 2**

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<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



#### **SOT-23 (TO-236)** CASE 318 ISSUE AT

**DATE 01 MAR 2023** 

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	1	
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13: PIN 1. SOURCE 2. DRAIN 3. GATE	STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE	STYLE 18: PIN 1. NO CONNECTION 2. CATHODE 3. ANODE	STYLE 19: N PIN 1. CATHODE 2. ANODE 3. CATHODE-ANODE	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 24: PIN 1. GATE 2. DRAIN 3. SOURCE	STYLE 25: PIN 1. ANODE 2. CATHODE 3. GATE	STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

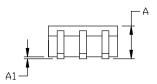
**DATE 11 APR 2023** 

#### NOTES:

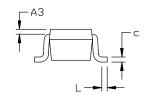
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

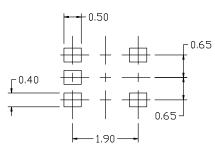
DIM	MILLIMETERS		
ויודת	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3	0,20 REF		
b	0.10	0.20	0.30
C	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2.20
E1	1.15	1.25	1.35
е		0.65 BSI	
L	0.10	0.15	0.30

# е Ε1 0 5X b



◆ 0.2 M B M





#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:
PIN 1. BASE
<ol><li>EMITTER</li></ol>
3. BASE
<ol><li>COLLECTOR</li></ol>
<ol><li>COLLECTOR</li></ol>

3. EMITTER 1

4. COLLECTOR

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

3. BASE

4. COLLECTOR

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1

4. BASE

5. EMITTER

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

3. ANODE 4. ANODE

ANODE
 ANODE

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

out in the datasheet refer to the device

datasheet pinout or pin assignment.

STYLE 6: STYLE 7: STYLE 8: STYLE 9: Note: Please refer to datasheet for PIN 1. EMITTER 2 PIN 1. CATHODE 2. COLLECTOR 3. N/C PIN 1. ANODE 2. CATHODE PIN 1. BASE style callout. If style type is not called 2. EMITTER 2. BASE 2

5. COLLECTOR 2/BASE 1 5. COLLECTOR **DOCUMENT NUMBER:** 98ASB42984B

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BAS20LT3G NSVBAS19LT1G NSVBAS20LT3G SBAS21DW5T3G